

BY500-50 – BY500-1000

FAST RECOVERY RECTIFIER DIODES

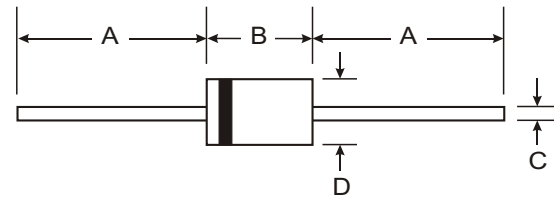
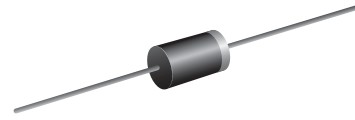
VOLTAGE RANGE: 50 - 1000V
CURRENT: 5.0 A

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-201		
Dim	Min	Max
A	25.40	—
B	8.50	9.53
C	0.96	1.06
D	4.80	5.21
All Dimensions in mm		



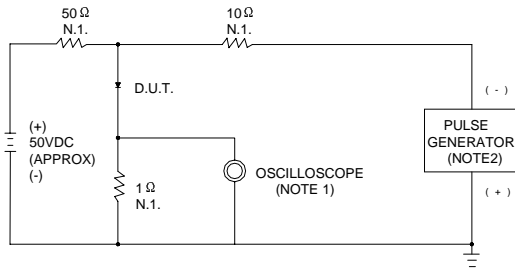
Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	BY500-50	BY500-100	BY500-200	BY500-400	BY500-600	BY500-800	BY500-1000	Unit
Peak Repetitive Reverse Voltage	V _{RRM}								V
Working Peak Reverse Voltage	V _{RWM}	50	100	200	400	600	800	1000	
DC Blocking Voltage	V _R								
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T _A = 75°C	I _O	5.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	200							A
Forward Voltage @I _F = 5.0A	V _{FM}	1.3							V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	10 1000							μA
Maximum reverse recovery time (Note1)	t _{rr}	200							ns
Typical Junction Capacitance (Note 2)	C _j	55							pF
Typical Thermal Resistance Junction to Ambient (Note 1)	R _{θJA}	15							°C/W
Operating Temperature Range	T _j	-65 to +125							°C
Storage Temperature Range	T _{STG}	-65 to +150							°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
 2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.

FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ, 22pF
 2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω

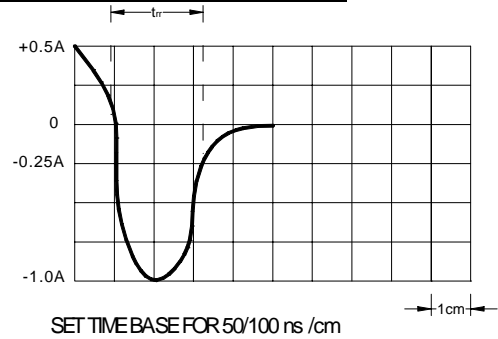


FIG.2 – FORWARD DERATING CURVE

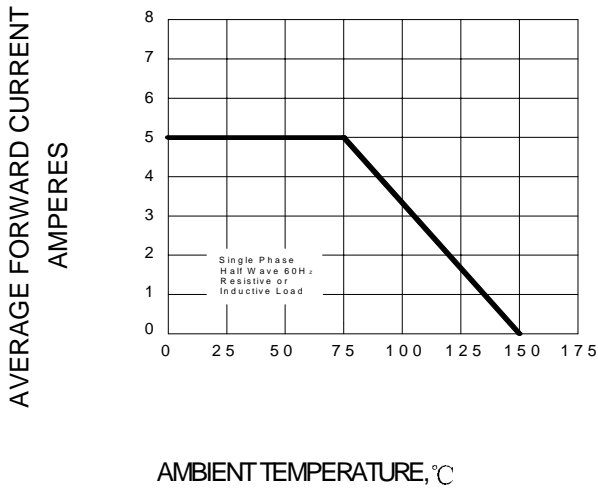


FIG.3 – PEAK FORWARD SURGE CURRENT

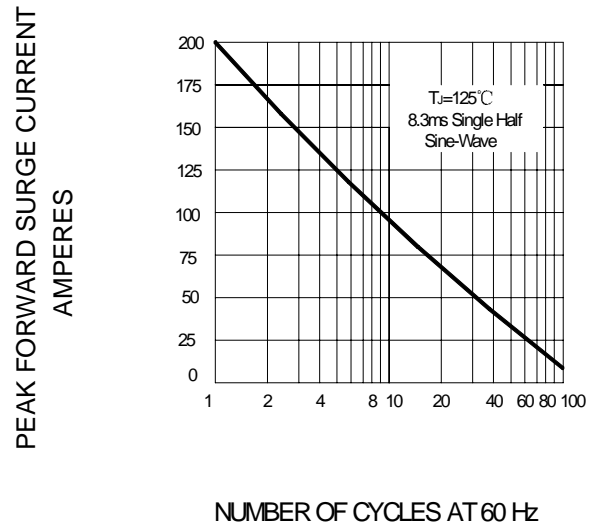


FIG.4 – TYPICAL FORWARD CHARACTERISTIC

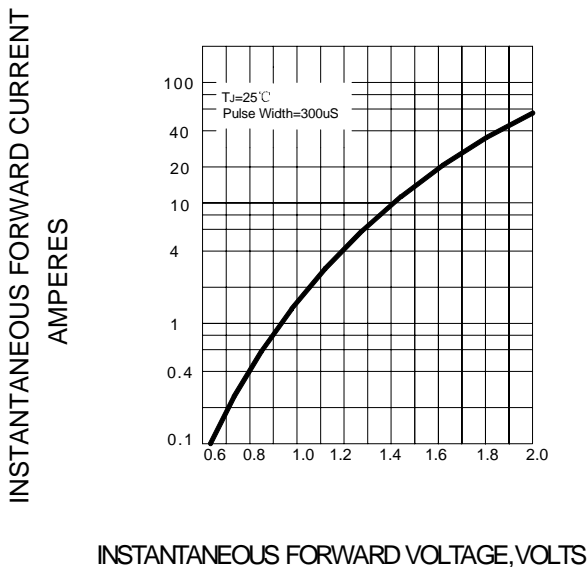
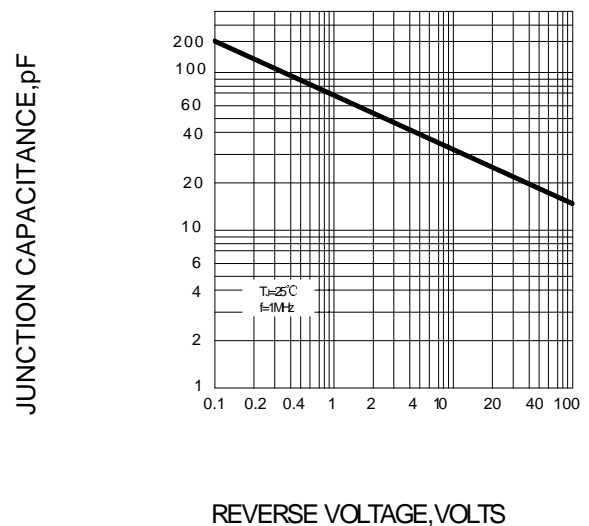


FIG.5 – TYPICAL JUNCTION CAPACITANCE



单击下面可查看定价，库存，交付和生命周期等信息

[>>SUNMATE\(森美特\)](#)